# 0.6Ω, Low-Voltage, Single-Supply, Dual SPDT Analog Switch

#### **General Description**

The MAX4736 is a low on-resistance, low-voltage, dual single-pole/double throw (SPDT) analog switch that operates from a single 1.6V to 4.2V supply. This device has fast switching speeds ( $t_{ON}$  = 25ns,  $t_{OFF}$  = 20ns max), handles rail-to-rail analog signals, and consumes less than 4µW of quiescent power. The MAX4736 has breakbefore-make switching.

When powered from a 3V supply, the MAX4736 features low 0.6 $\Omega$  on-resistance (R<sub>ON</sub>), with 0.1 $\Omega$  R<sub>ON</sub> matching and 0.05 $\Omega$  R<sub>ON</sub> flatness. The digital logic input is 1.8V CMOS compatible when using a single 3V supply.

The MAX4736 has one normally open (NO) switch and one normally closed (NC) switch, and is available in 12-pin TQFN (3mm x 3mm), 10-pin  $\mu$ MAX, and 10-pin  $\mu$ DFN (2mm x 2mm) packages.

#### **Applications**

- Power Routing
- Battery-Powered Systems
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Communications Circuits
- PCMCIA Cards
- Cellular Phones
- Modems
- Hard Drives

## **Benefits and Features**

- Low R<sub>ON</sub> 0.6Ω (3V Supply) 1.5Ω (1.8V Supply)
- 0.1Ω max R<sub>ON</sub> Flatness (3V Supply)
- Single-Supply Operation Down to 1.6V
- Available in TQFN, µDFN, and µMAX Packages
- 1.8V CMOS Logic Compatible (3V Supply)
- Fast Switching: t<sub>ON</sub> = 25ns, t<sub>OFF</sub> = 20ns

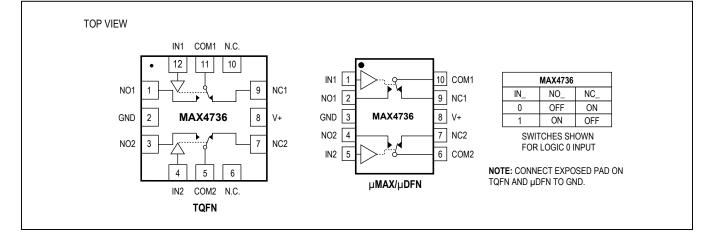
#### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX4736EUB+	-40°C to +85°C	10 µMAX
MAX4736EUB+T	-40°C to +85°C	10 µMAX
MAX4736ETC+	-40°C to +85°C	12 TQFN (3mm x 3mm)
MAX4736ETC+T	-40°C to +85°C	12 TQFN (3mm x 3mm)
MAX4736ELB+	-40°C to +85°C	10 µDFN (2mm x 2mm)
MAX4736ELB+T	-40°C to +85°C	10 µDFN (2mm x 2mm)

T = Tape and reel.

+Denotes lead(Pb)-free/RoHS-compliant package.

## Pin Configurations/Functional Diagrams/Truth Table





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### **Absolute Maximum Ratings**

(Voltages referenced to GND.)	
V+, IN	0.3V to +4.6V
COM_, NO_, NC_ (Note 1)	0.3V to (V+ + 0.3V)
Continuous Current COM_, NO_, NC	±300mA
Continuous Current (all other pins)	±20mA
Peak Current COM_, NO_, NC_	
(pulsed at 1ms 10% duty cycle)	±500mA

Storage Temperature Range65°C to +150°C	Continuous Power Dissipation ( $T_A = +70^{\circ}$ C) 10-Pin µDFN (derate 5.3mW/°C above +70°C)423.7mW 10-Pin µMAX (derate 5.6mW/°C above +70°C)444mW 12-Pin TQFN (derate 14.7mW/°C above +70°C)1176mW Operating Temperature Range40°C to +85°C Maximum Junction Temperature+150°C Storage Temperature Range
Storage Temperature Range65°C to +150°C Lead Temperature (soldering, 10s)+300°C Soldering Temperature (reflow)+260°C	Storage Temperature Range65°C to +150°C Lead Temperature (soldering, 10s)+300°C

**Note 1:** Signals on COM\_, NO\_, or NC\_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **Electrical Characteristics—Single 3V Supply**

(V+ = 2.7V to 4.2V, V<sub>IH</sub> = 1.4V, V<sub>IL</sub> = 0.5V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are at V+ = 3.0V, T<sub>A</sub> = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V <sub>COM</sub> _, V <sub>NO</sub> _, V <sub>NC</sub> _			0		V+	V	
		V+ = 2.7V ,	+25°C		0.6	0.8	0	
On-Resistance (Note 4)	R <sub>ON</sub>	I <sub>COM</sub> _ = 100mA; V <sub>NO</sub> _ or V <sub>NC</sub> _ = 1.5V	T <sub>MIN</sub> to T <sub>MAX</sub>			1	Ω	
On-Resistance Match Between Channels (Notes 4, 5)	$\Delta R_{ON} \qquad \begin{array}{c} V + = 2.7V , \\ I_{COM} = 100 \text{mA}; \\ V_{NO} \text{ or } V_{NC} = 1.5V \end{array}$	+25°C		0.1	0.2			
			T <sub>MIN</sub> to T <sub>MAX</sub>		0.3		Ω	
On-Resistance Flatness (Note 6)	R <sub>FLAT(ON)</sub>	V+ = 2.7V, I <sub>COM</sub> = 100m A; V <sub>NO</sub> or V <sub>NC</sub> = 1V, 1.5V, 2V	+25°C		0.05	0.1	0	
			T <sub>MIN</sub> to T <sub>MAX</sub>		0.2		Ω	
NO_or NC_Off-Leakage Current (Note 10)	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	· · ·	+25°C	-1	±0.002	+1	24	
		$V_{COM} = 0.3V, 3.3V,$ $V_{NO}$ or $V_{NC} = 3.3V, 0.3V$	T <sub>MIN</sub> to T <sub>MAX</sub>	-5		+5	nA	
COM_ On-Leakage Current (Note 10)		V <sub>COM</sub> = 0.3V, 3.3V;	+25°C	-2	±0.002	+2	nA	
		V <sub>NO</sub> _or V <sub>NC</sub> _= 0.3V, 3.3V, or floating	$T_{MIN}$ to $T_{MAX}$	-10		+10		

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#### **Electrical Characteristics—Single 3V Supply (continued)**

(V+ = 2.7V to 4.2V, V<sub>IH</sub> = 1.4V, V<sub>IL</sub> = 0.5V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are at V+ = 3.0V, T<sub>A</sub> = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
SWITCH DYNAMIC CHARA	CTERISTICS		1 1				,
Turn-On Time	ton	V <sub>NO_</sub> , V <sub>NC_</sub> = 1.5V; R <sub>L</sub> = 50Ω, C <sub>L</sub> = 35pF,	+25°C		20	25	ns
Tum-On Time	UN	Figure 1	$T_{MIN}$ to $T_{MAX}$			30	113
Turn-Off Time	torr	V <sub>NO_</sub> , V <sub>NC</sub> _ = 1.5V; R <sub>L</sub> = 50Ω, C <sub>L</sub> = 35pF,	+25°C		15	20	ne
	tOFF	Figure 1	$T_{MIN}$ to $T_{MAX}$			25	— ns
Break-Before-Make	toou	V <sub>NO_</sub> , V <sub>NC_</sub> = 1.5V; R <sub>L</sub> = 50Ω, C <sub>L</sub> = 35pF,	+25°C		5		
(Note 7)	<sup>t</sup> ввм	Figure 2	$T_{MIN}$ to $T_{MAX}$	1			ns
Charge Injection	Q	V <sub>GEN</sub> = 0, R <sub>GEN</sub> = 0, C <sub>L</sub> = 1.0nF, Figure 3	+25°C		60		рС
NO_ or NC_ Off- Capacitance	C <sub>OFF</sub>	f = 1MHz, Figure 4	+25°C		33		pF
COM_ Off-Capacitance	C <sub>COM(OFF)</sub>	f = 1MHz, Figure 4	+25°C		60		pF
COM_ On-Capacitance	C <sub>COM(ON)</sub>	f = 1MHz, Figure 4	+25°C		85		pF
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} =$ 50 $\Omega$ , $C_L =$ 5pF, Figure 5			130		MHz
Off-Isolation (Note 8)	V <sub>ISO</sub>	f = 1MHz, $V_{COM}$ = 1 $V_{P-P}$ , R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, Figure 5	+25°C		-52		dB
Crosstalk (Note 9)	V <sub>CT</sub>	f = 1MHz, $V_{COM}$ = 1 $V_{P-P}$ , R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, Figure 5	+25°C		-78		dB
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V <sub>COM</sub> = 2V <sub>P-P</sub> , R <sub>L</sub> = 32Ω	+25°C		0.018		%
LOGIC INPUT (A_, IN_)	1	I					1
Input Logic High	VIH			1.4			V
Input Logic Low	VIL					0.5	V
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> _ = 0 or 3.6V		-1	+0.005	+1	μA
POWER SUPPLY	·	·					
Power-Supply Range	V+			1.6		3.6	V
Positive Supply Current	+	V+ = 3.6V, V <sub>IN</sub> _ = 0 or V+, all channels on or off			0.006	1	μA

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#### **Electrical Characteristics—Single 1.8V Supply**

(V+ = 1.8V,  $V_{IH}$  = 1.0V,  $V_{IL}$  = 0.4V,  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified. Typical values are at  $T_A$  = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH	<b>I</b>	J					1
Analog Signal Range	V <sub>COM_</sub> , V <sub>NO_</sub> , V <sub>NC_</sub>			0		V+	V
On-Resistance	Paul	I <sub>COM</sub> = 100mA;	+25°C		1.5	2	Ω
On-Resistance	R <sub>ON</sub>	$V_{NO}$ or $V_{NC}$ = 1V	T <sub>MIN</sub> to T <sub>MAX</sub>			3	
SWITCH DYNAMIC CHAP	RACTERISTICS						
Turn-On Time	t <sub>ON</sub>	$V_{NO}$ , or $V_{NC}$ = 1V; R <sub>I</sub> = 50 $\Omega$ , C <sub>I</sub> = 35pF,	+25°C		25	30	ns
		Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			35	113
Turn-Off Time	tOFF	$V_{NO}$ , or $V_{NC}$ = 1V; R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 35pF, Figure 1	+25°C		18	25	- ns
			T <sub>MIN</sub> to T <sub>MAX</sub>			28	
Break-Before-Make	toou	$V_{NO}$ , or $V_{NC}$ = 1V; R <sub>I</sub> = 50 $\Omega$ , C <sub>I</sub> = 35pF,	+25°C		7		ns
(Note 7)	<sup>t</sup> BBM	Figure 2	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	1			115
Charge Injection	Q	$V_{GEN}$ = 0, $R_{GEN}$ = 0, $C_L$ = 1nF, Figure 3	+25°C		35		рС
Off-Isolation (Note 8)	V <sub>ISO</sub>	$    f = 1MHz, V_{NO} = V_{NC} $ $    = 1V_{P-P}, R_L = 50\Omega, $ $    C_L = 5pF, Figure 5 $	+25°C		-52		dB
Crosstalk (Note 9)	V <sub>CT</sub>	$ \begin{array}{l} \mbox{f = 1MHz, V_{COM} = 1V_{P-P},} \\ \mbox{R}_L = 50\Omega, \mbox{C}_L = 5pF, \mbox{ Figure 5} \end{array} $	+25°C		-78		dB
LOGIC INPUT (IN_)		,					
Input Logic High	VIH			1			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 0 or 3.6V				1	μA

**Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

**Note 3:** -40°C specifications are guaranteed by design.

Note 4:  $R_{ON}$  and  $\Delta R_{ON}$  matching specifications for TQFN packaged parts are guaranteed by design.

Note 5:  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

Note 6: Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Guaranteed by design.

**Note 8:** Off-Isolation =  $20\log_{10}(V_{COM}/V_{NO})$ ,  $V_{COM}$  = output,  $V_{NO}$  = input to OFF switch.

Note 9: Between two switches.

Note 10: Leakage parameters are 100% tested at hot temperature and guaranteed by correlation at room.

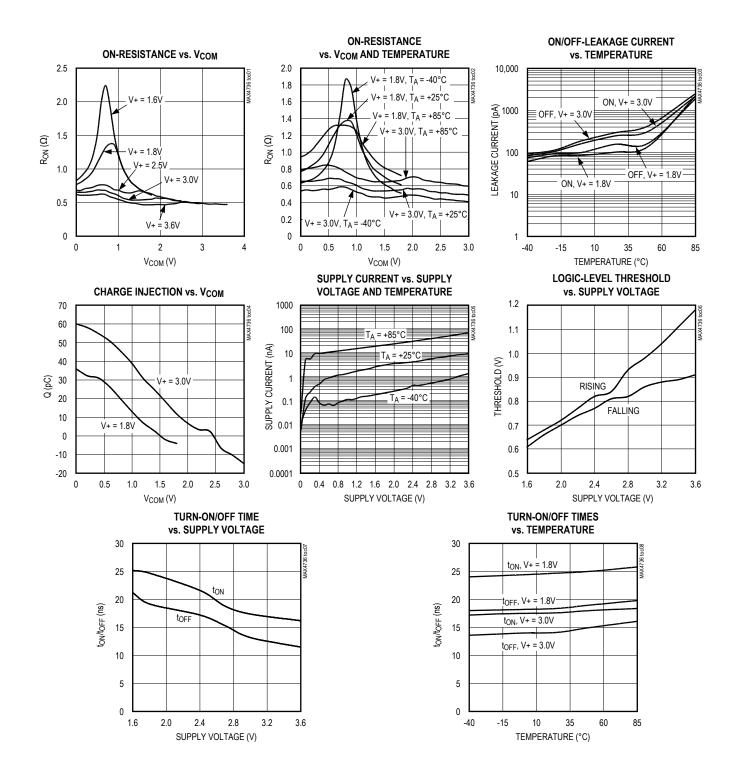
Note 11: Devices are guaranteed to 1 million cycles of operation. (Cycle = switch on  $\rightarrow$  switch off  $\rightarrow$  switch on)

**Note 12:** The minimum load resistance is  $8\Omega$ .

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## **Typical Operating Characteristics**

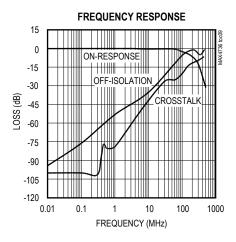
(T<sub>A</sub> = +25°C, unless otherwise noted.)

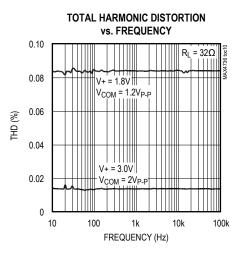


# 0.6Ω, Low-Voltage, Single-Supply, Dual SPDT Analog Switch

## **Typical Operating Characteristics (continued)**

 $(T_A = +25^{\circ}C, unless otherwise noted.)$ 





#### **Pin Description**

PIN			FUNCTION	
µMAX/µDFN	TQFN	NAME	FUNCTION	
1	12	IN1	Digital Control Input Switch 1	
2	1	NO1	Analog Switch 1—Normally Open Terminal	
3	2	GND	Ground	
4	3	NO2	Analog Switch 2—Normally Open Terminal	
5	4	IN2	Digital Control Input Switch 2	
6	5	COM2	Analog Switch 2—Common Terminal	
7	7	NC2	Analog Switch 2—Normally Closed Terminal	
8	8	V+	Positive-Supply Voltage Input	
9	9	NC1	Analog Switch 1—Normally Closed Terminal	
10	11	COM1	Analog Switch 1—Common Terminal	
	6,10	N.C.	No Connection	
—	EP	EP	Exposed Pad. Connect to ground.	

#### **Detailed Description**

The MAX4736 is a low  $0.8\Omega$  max (at V+ = 2.7V) onresistance, low-voltage, dual SPDT analog switch that operates from a 1.6V to 4.2V single supply. CMOS switch construction allows switching analog signals that range from GND to V+.

When powered from a 2.7V supply, the  $0.8\Omega$  max R<sub>ON</sub> allows high continuous currents to be switched in a variety of applications.

#### **Applications Information**

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings; stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO\_, NC\_, or COM\_.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A  $0.1\mu$ F capacitor, connected from V+ to GND, is adequate for most applications.

#### Logic Inputs

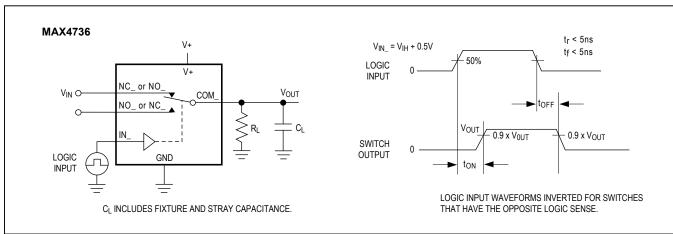
The MAX4736 logic inputs can be driven up to 3.6V, regardless of the supply voltage. For example, with a 1.8V supply, IN\_ can be driven low to GND and high to 3.6V. Driving IN\_ rail-to-rail minimizes power consumption.

#### **Analog Signal Levels**

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO\_, NC\_, and COM\_ pins can be used as either inputs or outputs.

#### Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.



#### Figure 1. Switching Time

## **Test Circuits/Timing Diagrams**

# 0.6Ω, Low-Voltage, Single-Supply, Dual SPDT Analog Switch

## **Test Circuits/Timing Diagrams (continued)**

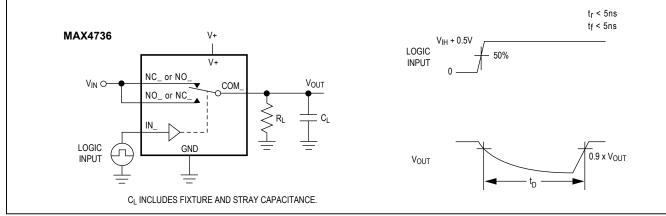


Figure 2. Break-Before-Make Interval

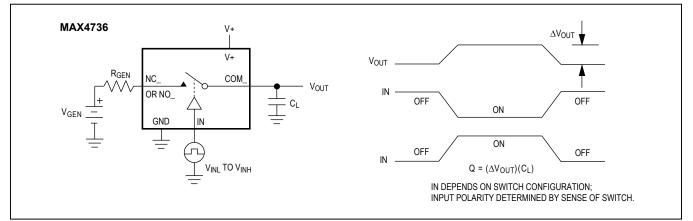


Figure 3. Charge Injection

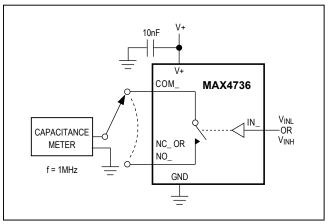


Figure 4. Channel Off/On-Capacitance

## **Chip Information**

TRANSISTOR COUNT: 379 PROCESS: CMOS

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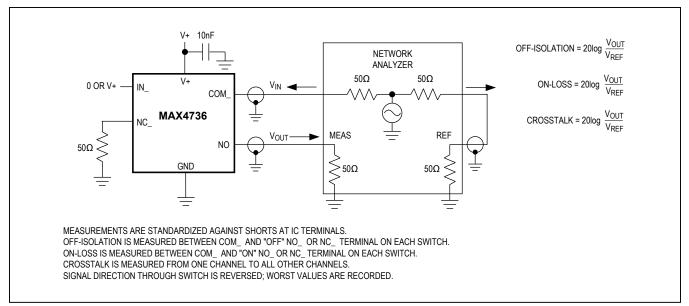


Figure 5. On-Loss, Off-Isolation, and Crosstalk

#### **Package Information**

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
10 MDFN	L1022+1	<u>21-0164</u>	<u>90-0006</u>
10 MMAX	U10+2	<u>21-0061</u>	<u>90-0330</u>
12 TQFN	T1233+1	<u>21-0136</u>	<u>90-0066</u>

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#### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
3	1/14	Added QFN package	1, 2, 4, 6, 10
4	11/16	Removed reference to EV kit manual, QFN package option, and corrected Ordering Information table	1, 2, 4, 6, 9

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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